| L Number | Hits | Search Text | DB | Time stamp |
|---|---|---|---|---|
| 1 | 5168 | ferroelectric near memory | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/12/15 15:33 |
| 2 | 2692 | transistor and (ferroelectric near capacitor) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/12/15 15:34 |
| 3 | 281 | matrix and (ferroelectric near memory) and (transistor and (ferroelectric near capacitor)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/12/15 15:36 |
| 4 | 34242 | (word near line) and (bit near line) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/12/15 15:44 |
| 5 | 234 | (matrix and (ferroelectric near memory) and (transistor and (ferroelectric near capacitor))) and ((word near line) and (bit near line)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/12/15 15:44 |